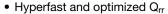


Hyperfast Rectifier, 30 A FRED Pt® G5



PRIMARY CHARACTERISTICS						
I _{F(AV)}	30 A					
V _R	1200 V					
V _F at I _F at 125 °C	2.1 V					
t _{rr}	26 ns					
T _J max.	175 °C					
Package	D ² PAK 2L (TO-263AB 2L)					
Circuit configuration	Single					

FEATURES





• Best in class forward voltage drop and switching RoHS losses trade off

HALOGEN FREE

• Optimized for high speed operation

- 175 °C maximum operating junction temperature
- Polyimide passivation
- Meets MSL level, per J-Std-020, LF maximum peak of 245 °C
- AEC-Q101 gualified meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: D²PAK 2L (TO-263AB 2L)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Repetitive peak reverse voltage	V_{RRM}		1200	V				
Average rectified forward current	I _{F(AV)}	T _C = 83 °C, D = 0.50	30					
Non-repetitive peak surge current	I _{FSM}	T_C = 83 °C, t_p = 10 ms, sine wave	190	Α				
Repetitive peak forward current	I _{FRM}	$T_C = 45 ^{\circ}\text{C}, D = 0.50, f = 20 \text{kHz}$	60					
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	1200	-	-			
Forward voltage	W	I _F = 30 A	-	2.6	3.3	V		
	V _F	I _F = 30 A, T _J = 125 °C	-	2.1	-	,		
Reverse leakage current	I _R	$V_R = V_R$ rated	-	-	50			
		T _J = 125 °C, V _R = V _R rated	-	-	500	μA		
Junction capacitance	C _T	V _R = 200 V	-	17	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH		





DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST (TEST CONDITIONS			MAX.	UNITS	
		$I_F = 1.0 \text{ A}, dI_F/dt$	$t = 100 \text{ A/}\mu\text{s}, V_{R} = 30 \text{ V}$	ı	26	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		ı	100	-	ns	
		T _J = 125 °C		ı	150	-		
Pook roomyony ourrent	1	T _J = 25 °C	l _F = 20 A dl _F /dt = 600 A/μs	ı	12	-	Α	
Peak recovery current	I _{RRM}	T _J = 125 °C	$V_{R} = 400 \text{ V}$	ı	22	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	530	-	nC	
neverse recovery charge		T _J = 125 °C		-	1650	-		
Davages resource time		T _J = 25 °C		-	80	-	ns	
Reverse recovery time	t _{rr}	T _J = 125 °C		-	120	-		
Dools was a surveyed		T _J = 25 °C	$I_F = 30 \text{ A}$	-	22	-	Α	
Peak recovery current	I _{RRM}	T _J = 125 °C	dl _F /dt = 1000 A/μs V _B = 800 V	-	37	-	A	
Poverse receivery charge	0	T _J = 25 °C]	-	900	-	nC	
Reverse recovery charge	Q_{rr}	T _J = 125 °C		-	2400	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.1	°C/W		
Weight			-	2.0	-	g		
vveigni			-	0.07	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style D ² PAK 2L (TO-263AB 2L)) E5TX3012SH					



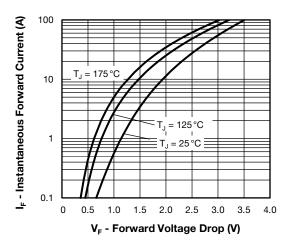


Fig. 1 - Typical Forward Voltage Drop Characteristics

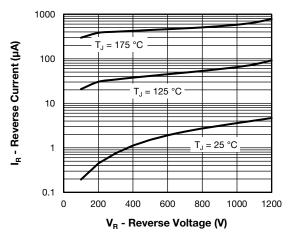


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

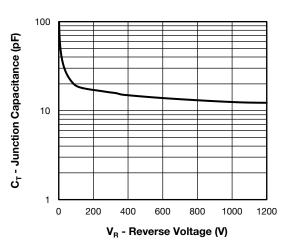


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

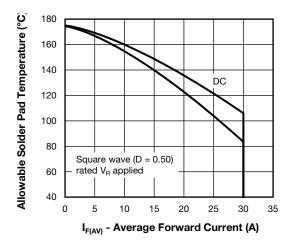


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

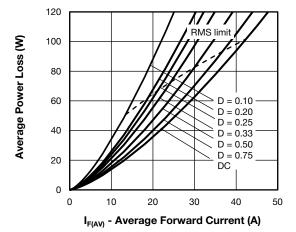


Fig. 5 - Typical Recovery Current vs. dl_F/dt

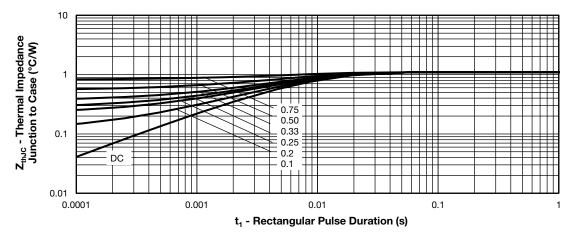


Fig. 6 - Thermal Impedance Z_{thJC} Characteristics

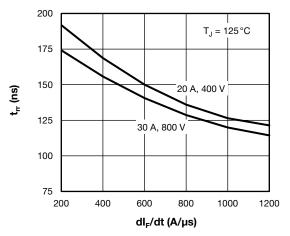


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

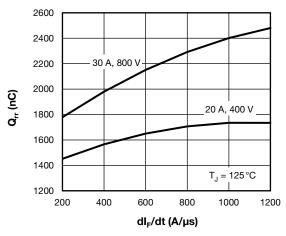


Fig. 8 - Typical Stored Charge vs. dl_F/dt

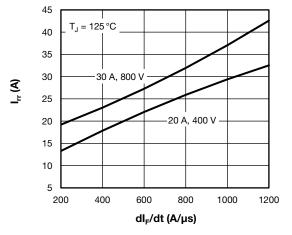


Fig. 9 - Typical Recovery Current vs. dl_F/dt

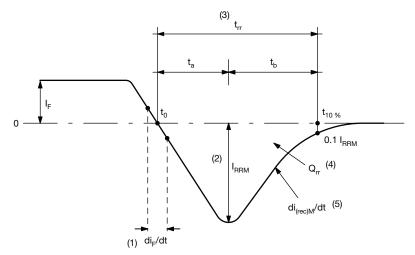


Fig. 10 - Reverse Recovery Waveform and Definitions

Notes

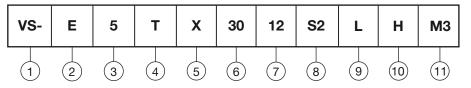
- (1) di_E/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RBM}
- $^{(4)}$ Q_{rr} area under curve defined by t₀ and t_{10 %}

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t)dt$$

(5) di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 E = single diode
- **3** 5 = FRED generation 5
- 4 Package:
 - $T = D^2PAK$ (TO-262) package
- 5 X = hyperfast recovery
- 6 Current rating (30 = 30 A)
- 7 Voltage rating (12 = 1200 V)
- 8 S2 = true 2 pin D^2PAK
- 9 None = tube (50 pieces)
 - L = tape and reel (left oriented, for D²PAK package)

If needed different orientation/packaging, please contact factory

- 10 H = AEC-Q101 qualified
- 11 Environmental digit:

M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free



VS-E5TX3012S2LHM3

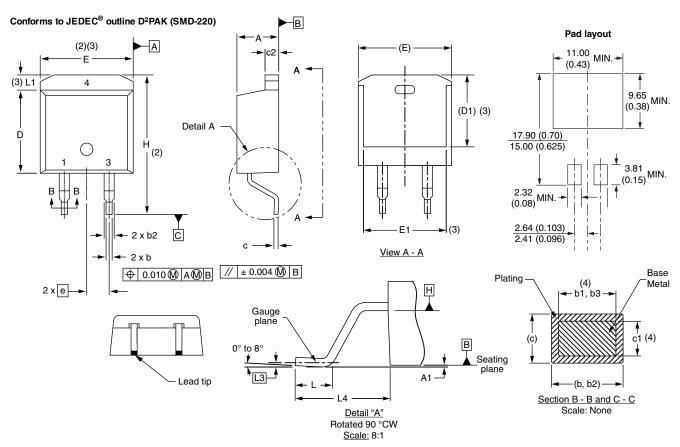
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-E5TX3012S2LHM3	800	800	13" diameter reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96683				
Part marking information	www.vishay.com/doc?96693				
Packaging information	www.vishay.com/doc?95032				



2L-D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIMETERS INCHES		NOTES		
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L3	0.25 BSC		0.010) BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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Vishay

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